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Ferroelectricity coexisted with *p*-orbital ferromagnetism and metallicity in two-dimensional metal oxynitrides

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Two-dimensional (2D) multiferroics have attracted increasing interests in basic science and technological fields in recent years. However, most reported 2D magnetic ferroelectrics are based on the *d*-electron magnetism, which makes them rather rare due to the empirical d^0 rule and limits their applications for low magnetic phase transition temperature. In this work, we demonstrate that the ferroelectricity can coexist with the *p*-electron-induced ferromagnetism without the limitation of d^0 rule and metallicity in a family of stable 2D MXene-analogous oxynitrides, X_2NO_2 (X = In, TI). Remarkably, the itinerant character of *p* electrons can lead to the strong ferromagnetic metallic states. Furthermore, a possible magnetoelectric effect is manifested in a Tl₂NO₂/WTe₂ heterostructure through the interface engineering. Our findings provide an alternative possible route toward 2D multiferroics and enrich the concept of ferroelectric metals.

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INTRODUCTION

Multiferroic materials integrating spontaneous ferroelectric and magnetic long-range orders¹⁻⁴ have aroused great interests in recent decades as they not only offer a vigorous platform for discovering emergent phenomena in condensed-matter physics^{2,5}, such as skyrmions⁶ and electromagnons⁷, but also have transformative technological potential⁸ in the high-density nonvolatile memory devices, owing to multiple logic states⁹ and magnetoelectric effects^{4,8,10}. Although electronic polarization and magnetization can be tightly coupled together within macroscopic electrodynamics, in a sense, they are typically incompatible in a single-phase material, which makes multiferroic materials highly scarce^{5,11}. Commonly, the d orbitals occupied by the unpaired electrons, which give rise to magnetic moments, suppress the ferroelectric distortion¹² that usually requires empty d orbitals (so-called d^0 rule)^{8,11}. To bypass this limitation, several mechanisms have been proposed in single-phase multiferroics⁸, including lone pair ferroelectricity (FE) + d-electron magnetism (e.g. BiFeO₃)¹³, d^0 FE + f-electron magnetism (e.g. strained $EuTiO_3$)¹⁴, geometrically driven multiferroics (e.g. YMnO₃)², charge-ordering driven FE (e.g. Fe₃O₄)⁸, and spin-ordering driven FE (e.g. TbMnO₃)¹⁵. However, the independent origins of FE and magnetism in type-I multiferroics within these strategies result in the extremely weak magnetoelectric effect^{3,5,11}, while the FE order induced by magnetic spirals in type-II multiferroics is usually accompanied by small electric polarization (~ $10^{-2} \,\mu C(cm)^{-2}$) and low Curie temperature^{2,3,5,8}, which severely hinder their practical applications. Hence, alternative mechanisms for the design of multiferroics that can work above room temperature and hold strong magnetoelectric coupling are urgently needed in fundamental physics and applications⁸.

Recently, two-dimensional (2D) multiferroics^{16–20} are the rising stars since the confirmation of 2D ferroelectrics (e.g. α -ln₂Se₃)²¹

and magnetic van der Waals (vdW) materials (such as Crl₃ and Fe₃GeTe₂ monolayer)²². Compared with conventional multiferroics, 2D counterparts with different properties, such as no surface dangling bonds²³ and atomic thickness²⁰, are promising for the miniaturization of devices and ultra-high-speed storage²⁴. Actually, a number of 2D multiferroics have been reported theoretically or experimentally, including type-II multiferroics (Hf₂VC₂F₂ MXene)¹⁹ and type-I multiferroics ((CrBr₃)₂Li monolayer²⁰ $CuCrP_2S_6^{18}$, and VOX_2 (X = Cl, Br, I)^{16,17}). As expected, their magnetism originates from *d* electrons and the magnetic transition temperatures are usually low. As a matter of fact, p orbitals can also induce high-temperature ferromagnetism, namely d^0 magnetism²⁵, which has been verified in many systems such as nitrogen-doped graphene²⁶ and carbon-doped ZnO²⁷, but are rarely involved in 2D multiferroics within conventional mechanisms yet. Whether the intrinsic ferroelectricity can coexist and interact with the p-orbital ferromagnetism beyond the d^0 rule or not in 2D crystal has still been under debate.

In this work, we report an alternative route for 2D multiferroics without the d^0 -rule requirement within a family of stable 2D MXene-analogous oxynitrides, X_2NO_2 (X = In, Tl). We show that these materials represent a class of *p*-orbital multiferroic metals, where the ferroelectricity and intrinsic ferromagnetism can stem from the same N ion. We demonstrate that the spin-polarized N- $2p_x/2p_y$ electrons show an itinerant character, which can give rise to the metallicity and the strong ferromagnetism with a high Curie temperature. Interestingly, the intrinsic and strain-induced ferroelectricities driven by the offset displacement of N ion are predicted in Tl₂NO₂ and In₂NO₂ monolayers, respectively. Therefore, the X_2NO_2 monolayers may belong to the long-sought-after 'ferroelectric metals', which was proposed by Anderson et al. in 1965²⁸ and confirmed in the bulk LiOsO₃²⁹ and bilayer WTe₂³⁰ recently.

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Furthermore, a magnetoelectric effect is predicted in a $TI_2NO_2/$ WTe_ heterostructure via the interface interaction.

RESULTS AND DISCUSSION

Atomic structures and stability

Recent observations of ferroelectricity in 2D $\ln_2Se_3^{21}$ as well as magnetic properties in N-doped $\ln_2O_3^{31}$ have raised the possibility of multiferroelectricity in two-dimensional oxynitrides, which motivated us to design a family of 2D oxynitrides X_2NO_2 (X = In, Tl). Firstly, to investigate the most stable atomic structures of the X_2NO_2 (X = In, TI) monolayers, we considered 53 possible structural configurations (Supplementary Fig. 1, 2) reported by Ding et al.³², including fcc, FE-ZB', and FE-WZ' phases. The lattice parameters and formation energy of each structure are shown in Supplementary Tables 1–4. For the Tl₂NO₂ monolayer, the FE–WZ' phase (Supplementary Tables 1, 2) with the symmetric stacking sequence of O-TI-N-TI-O is the most stable structure for its lowest formation energy (0.279 eV per atom), which is slightly lower than those of the FE-ZB' (0.280 eV per atom) and fcc phases (0.295 eV per atom). Such value is much smaller than that of the successfully synthesized silicene (0.744 eV per atom)³³, implying a good stability and possible fabrication of the Tl₂NO₂ monolayer. In contrast, the U₂₄ phase with the asymmetric stacking sequence of N-In-O-In-O has the lowest formation energy (-0.499 eV per atom) for the In₂NO₂ monolayer (Supplementary Tables 3, 4), while its fcc phase has the lowest formation energy (-0.493 eV per)atom) among structures with a symmetric stacking sequence of O-In-N-In-O. As the formation energies of U₂₄ and fcc phases for the In₂NO₂ monolayer are negative and guite close to each other, both could be synthesized using the atomic layer-by-layer molecular-beam epitaxy deposition techniques, by which the sequences of atomic layers (N-In-O-In-O and O-In-N-In-O) may be precisely controlled³⁴. In addition, the FE-ZB' and FE-WZ' In₂NO₂ monolayers show similar energy, slightly higher than that of the fcc phase. Similar results can be obtained by using the DFT-D3 method³⁵, which accounts for the vdW interactions (Supplementary Table 5). It can be found that an attainable in-plane biaxial tensile strain larger than 2.6 % can trigger a phase transition from fcc to FE-ZB' for In₂NO₂ (Supplementary Fig. 3a, c). Hence, applying biaxial tensile strain may be an effective method to stabilize the FE-ZB' In_2NO_2 monolayer. However, for the Tl_2NO_2 monolayer, the FE-WZ' phase is always more energetically stable than the fcc and FE-ZB' phases under the attainable tensile strain (Supplementary Fig. 3b, d). Although the FE-ZB' and FE-WZ' phases are evidently quasi-degenerate in energy for the X_2NO_2 monolayers, they could be stabilized separately because of the sizable energy barriers between them³⁶ (Supplementary Fig. 4).

All the fcc, FE-ZB' and FE–WZ' phases consist of five triangularlattice atomic layers with a vertical stacking in the sequence of O– X–N–X–O (Fig. 1a–c). The centrosymmetric fcc phase with a point group of D_{3d} shares a similar structural characteristic with the synthesized oxygen-functionalized MXene³⁷, in which each central nitrogen atom equivalently bonds with the surrounding 6 metal atoms. Interestingly, in both FE-ZB' and FE–WZ' phases, the offcenter nitrogen atom coordinates tetrahedrally with four adjacent X atoms, forming three long X–N bonds and a short X–N bond oriented vertically (Supplementary Table 6). This results in a polar noncentrosymmetric structure with C_{3v} symmetry, similar to the case of 2D ferroelectric $\ln_2 Se_3^{21,32}$. Evidently, the inversion symmetry has been broken, and thus a vertical spontaneous polarization may be expected in these two phases.

The calculated phonon dispersions (Fig. 1d–f and Supplementary Fig. 5) and the ab initio molecular dynamics (AIMD)³⁸ simulations conducted for a 5×5 supercell (Supplementary Fig. 6) confirm that noncentrosymmetric FE-ZB' and FE–WZ' X_2 NO₂, as well as centrosymmetric fcc In₂NO₂, possess not only good



Fig. 1 Crystal structures and dynamic stability. Top and side views of X_2NO_2 monolayer with (**a**) fcc, (**b**) FE-ZB' and (**c**) FE-WZ' phase (dashed lines denote a unit cell). The phonon spectra of TI₂NO₂ monolayer with (**d**) fcc, (**e**) FE-ZB' and (**f**) FE-WZ' phase.

dynamical stability at 0 K, but also thermodynamical stability up to 300 K. However, the centrosymmetric fcc Tl₂NO₂ monolayer is not dynamically stable as there are two obvious imaginary optical phonon modes at Γ point, indicating spontaneous symmetry breaking in Tl₂NO₂ monolayer. We also explored the feasibility of the monolayer Al₂NO₂ and Ga₂NO₂ by the phonon dispersion spectra (Supplementary Fig. 5). We see that most of these structures (except fcc Al₂NO₂) are unlikely to be stable because of the obvious imaginary-frequency phonon modes. It is worth noting that the FE-ZB' and FE-WZ' phases for the X_2NO_2 (X = AI, Ga, In, and TI) monolayers become more stable with the increase of the atomic number of X (Al \rightarrow Tl). Furthermore, the mechanical stability of X₂NO₂ monolayer was also determined by calculating the elastic constants, $C_{11} = C_{22}$, C_{12} , and $C_{66} = (C_{11} - C_{12})/2$ within the standard Voigt notation after considering the symmetry of 2D hexagonal crystals (see details in Supplementary Note 1)³⁹. We show that all thermodynamically stable monolayers meet the Born-Huang criteria^{39,40} for 2D hexagonal crystal system, i.e. $C_{11} > |C_{12}|$ and $C_{11} > 0$, indicating their mechanical stabilities (Supplementary Table 7). The calculated in-plane Young's moduli of X₂NO₂ monolayers, which are comparable with 2D hexagonal Si⁴¹, as well as Poisson's ratio and ideal tensile strength, manifest their superior mechanical properties (more details can be found in Supplementary Note 1). In summary, all these results indicate that the stable and metastable phases of X_2NO_2 (X = In, TI) monolayers are experimentally feasible. As the FE-WZ' Tl₂NO₂ monolayer is the most stable structure, we will focus on it in the following parts unless otherwise stated.

Magnetic and ferroelectric properties

We proceed to focus on the magnetic and electronic properties of the FE–WZ' TI_2NO_2 monolayer. Although the *d* and *f* shells of the TI ion are full, the electron spin polarization can be found in the FE –WZ' TI_2NO_2 monolayer with a total magnetic moment of about 1.06 μ_B per unit cell (Supplementary Table 1). Subsequently, the magnetic ground state was determined by estimating the energies of three possible magnetic configurations, including collinear ferromagnetic (FM), collinear stripe antiferromagnetic (sAFM), and the 120° noncollinear antiferromagnetic (yAFM) spin orders¹⁹ (Supplementary Fig. 9). The FE–WZ' TI_2NO_2 monolayer is found to prefer a ferromagnetic ordering with a sizable exchange energy (defined as $E_{ex} = E_{sAFM} - E_{FM}$, where E_{sAFM} and E_{FM} are the



Fig. 2 Electronic and magnetic properties. a The spin-polarized band structure (left) and the element-resolved PDOS (right) at PBE level for FE–WZ' X_2NO_2 monolayer near the Fermi level, which is set to zero. Γ (0, 0, 0), M (1/2, 0, 0), and K (1/3, 1/3, 0) are the highly symmetric points in reciprocal space. **b** Top and side views of the spin charge density for sAFM and FM FE–WZ' X_2NO_2 monolayers. The isovalue is 0.1 electron per Å³. Spin-up and spin-down electrons are colored as cyan and orange, respectively. **c** Angle-dependent magnetic anisotropic energy with the magnetic moments lying on *xy*, *xz*, and *yz* planes. The energies for the case of the spin along the easy magnetization planes (*xy*/*xz*) are set to zero. The angles between the spin vector and the *x*, *y*, and *z* axes are shown in the inset. **d** The temperature dependence of the magnetic moment *M* (in red) and specific heat (in violet) of the FE–WZ' Tl₂NO₂ monolayer.

energies of sAFM and FM states, respectively) of 128.92 meV per N atom (Supplementary Table 8). The noncollinear yAFM state is unstable as it has the highest energy among these three magnetic configurations. We also find this FM ground state to be robust with the in-plane biaxial tensile strain even up to 6% (Supplementary Fig. 10). The local magnetic moment for N ion is about $0.6 \mu_{B}$. Interestingly, the O ion carries a local magnetic moment of $0.2\,\mu_B$ in the top surface layer, but nearly zero in the bottom surface layer (Supplementary Table 9), which shows an asymmetric spin density distribution. Unsurprisingly, there is no notable magnetic moment on the TI ions, in accord with the full-filled d and f electrons. The spin-resolved band structure (Fig. 2a) and the projected density of states (PDOS) (Supplementary Fig. 11) at the Perdew-Burke-Ernzerhof (PBE)⁴² level reveal that the N- $2p_x/2p_y$ orbitals are significantly spin-polarized, which is consistent with the spin density distributions (Fig. 2b), where the majority of spin density is found on the N atoms and a very small amount of it is found on the O atoms in the top surface layer. Furthermore, the spin-down bands around the Fermi level are mainly contributed by the N-2p and O-2p orbitals and show a similar metallic feature with the ferromagnetic transition metals induced by the itinerant d electrons, which coincides with the non-integer value of the magnetic moment. Moreover, one can find this itinerant ferromagnetic character to be relatively robust against the spin orbital coupling (SOC) (Supplementary Fig. 12) and biaxial in-plane tensile strain even up to 6% from band structures using the PBE (Supplementary Fig. 13) and Heyd-Scuseria-Ernzerhof hybrid (HSE06) functional⁴³ (Supplementary Fig. 14).

To further understand the origin behind this strong ferromagnetism and metallicity, we plot the band structure and the density of states (DOS) without considering the spin polarization (Supplementary Fig. 15) and find a relatively flat band mainly contributed by the N-2p orbitals along the Γ -M line near the Fermi level and a sharp peak of DOS at the Fermi level. The DOS at the Fermi level $D(E_F)$ equals 5.03 states per eV per N atom and the Stoner parameter *I* is about 0.97 eV. Thus, they meet the Stoner criterion for a stable ferromagnetic state⁴⁴, $D(E_F)I > 1$, which coincides with the positive exchange energy. This suggests that the relatively localized N-2*p* electrons, serving as itinerant electrons, can give rise to strong ferromagnetism and metallic feature. A similar mechanism has been reported in the hole-injected ZnO⁴⁴. Taken together, these results show that the FE $-WZ' TI_2NO_2$ monolayer is evidently a promising candidate for 2D ferromagnetic metal based on the d^0 magnetism. As such *p*-orbital ferromagnetism in this stable single-phase material is intrinsic and undoped, it should be strong and experimentally feasible in contrast to the impurity-induced ones.

In practical applications, the high magnetic anisotropy is desirable for the high-density magnetic storage, as it can lift the Mermin–Wagner restriction⁴⁵ in 2D systems and stabilize the longrange magnetic ordering against the thermal fluctuations. Therefore, the angle-dependent magnetic anisotropy energy (MAE) in the xz, yz, and xy planes were calculated by considering the SOC effect. One can see that the MAE of 2D FE-WZ' TI₂NO₂ possess the uniaxial anisotropy, which is a common feature of the hexagonal structures⁴⁶ (Fig. 2c). Specifically, the total energy varies significantly with the magnetization direction in the xz and yz planes, but is isotropic in the xy plane. Such strongly angledependent MAE along the z-direction has also been reported in other 2D magnetic materials, e.g. Fe₃GeTe₂⁴⁶. In contrast to Fe₃GeTe₂ and Crl₃, which have been confirmed as Ising ferromagnets with the out-of-plane easy axis^{45–47}, FE-WZ' Tl₂NO₂ exhibits an easy magnetic xy plane with a MAE up to about 166 µeV per N atom. Importantly, the MAE of FE-WZ' Tl₂NO₂ is much larger than those of some classical magnetic metals (in the order of µeV per atom)⁴⁸ and comparable to those of CrGeTe₃ monolayers (220 µeV per f.u.)⁴⁹.



Fig. 3 Ferroelectric properties. a Electrostatic potential curve of the relaxed monolayers along the *z*-direction. The electrostatic potential difference $(\Delta \Phi)$ is defined as the vacuum level difference between the top and bottom surfaces. **b** Top and side views of charge density differences between FE-WZ' and fcc Tl₂NO₂ (left), and between FE-ZB' and fcc In₂NO₂ (right). Green, yellow, and violet colors denote depleted charge, accumulated charge, and electric polarization, respectively. The isovalue is 1 electron per Å³. **c** The minimum energy pathway in the polarization reversal process for FE-WZ' Tl₂NO₂ monolayer. **d** Minimum energy pathway as a function of the in-plane biaxial tensile strain (from 0% to 5%) in the structural transition between two states with opposite electric polarization (**P** and -**P**) for the FE-ZB' In₂NO₂ monolayer. The transformation proceeds through a centrosymmetric structure in which the polarization is zero.

Table 1. Calculated electric dipole moments (p_e), electric polarizations (P_{2D} and P_{3D}), $\Delta \Phi$, and the activation barriers (E_{barrier}) in the polarization reversal process.					
System	p _e (eÅ per unit cell)	P _{2D} (pCm ⁻¹)	$P_{\rm 3D}~(\mu {\rm C}({\rm cm})^{-2})$	$\Delta \Phi$ (eV per unit cell)	E _{barrier} (eV per unit cell)
FE-ZB' In ₂ NO ₂	0.088	13.90	2.75	1.57	-
FE-ZB' In ₂ NO ₂ (+4%)	0.092	13.48	2.79	1.52	0.14
FE-WZ' TI ₂ NO ₂	0.045	6.60	1.26	0.75	0.65

Another key parameter to characterize the robustness of the ferromagnetic ordering is the Curie temperature $T_{\rm C}$. Although numerous 2D magnetic materials have been unveiled recently, 2D ferromagnetic ordering with a T_{C} above room temperature (~300 K) has been scarcely reported. For the FE-WZ' Tl₂NO₂ monolayer, the considerable exchange energy may lead to a high $T_{\rm C}$. The Curie temperature is evaluated to be 332 K within the mean field approximation by using $T_{\rm C} = \frac{2\triangle E}{3k_{\rm B}}$, where $\triangle E = \frac{E_{\rm ex}}{3}$ means the average exchange energy for each spin coupling interaction and $k_{\rm B}$ is Boltzmann's constant⁵⁰. As the total magnetic moment is very close to 1 μ_B , we also performed the Monte Carlo simulations based on the Heisenberg model to obtain a $T_{\rm C}$ more precisely (more details can be found in Supplementary Note 2). From the temperature-dependent magnetic moment and specific heat (Fig. 2d), the estimated Curie temperature is 415 K. Therefore, the $FE-WZ' TI_2NO_2$ monolayer might be a potential ferromagnetic metal working above room temperature. Additionally, the strong ferromagnetism, as well as the robust metallic feature, can also be found in FE-ZB' X₂NO₂ and FE-WZ' In₂NO₂ monolayers (see more details in Supplementary Figs. 10-14, Supplementary Figs. 17-21, and Supplementary Table 9).

In addition to ferromagnetism, ferroelectricity can also be anticipated in the FE–WZ' TI_2NO_2 monolayer. Taking the fcc phase as a reference, the mirror symmetry with respect to the *xy* plane is evidently broken in the FE–WZ' phase by the off-center displacement of the magnetic N atom. Such a structural distortion can be attributed to the imaginary optical phonon modes at Γ

point of fcc phase (Fig. 1a), which commonly induces a symmetrylowering phase transition according to the soft mode theory¹². From the electrostatic potential along the z-direction (Fig. 3a), one can find a vacuum level difference ($\Delta \phi$) of 0.75 eV (Table 1) between the top and bottom surfaces, which indicates the existence of the intrinsic out-of-plane dipole moment. The calculated out-of-plane electric dipole moment (pe) using the method suggested by Ding et al.³² is about 0.045 eÅ (Table 1), which corresponds to an out-of-plane spontaneous polarization of 6.6 pC m⁻¹ in the 2D unit (P_{2D}) or 1.3 μ C(cm)⁻² in the 3D unit (P_{3D}) (if the thickness is taken to be 5.2 Å). This value has the same order of magnitude as that of α -ln₂Se₃³² and is larger than those of some 2D materials with out-of-plane FE, such as $d1T MoS_2$ (0.18 μ C $(cm)^{-2})^{51}$ and 2D Hf₂VC₂F₂ (0.27 μ C(cm)⁻²)¹⁹. The electric polarization is also confirmed by the asymmetric spatial distribution of charge density difference between FE-WZ' and fcc phases (Fig. 3b). Clearly, the dipoles lying in the xy plane shows a threefold rotational symmetry and thus the net in-plane electric polarization is zero, which is consistent with the nature of C_{3v} symmetry.

Note that the position of the central N atom has two values, corresponding to two equivalent structures with the same energy but opposite electric polarizations pointing upward and downward. The minimum energy pathway connecting these two structures (Fig. 3c) shows that the polarization reversal process may go through a centrosymmetric paraelectric phase and the activation barrier (E_{barrier}) is about 0.65 eV per unit cell, comparable to those of some recently reported 2D ferroelectrics⁵² and bulk

 T_{d} -WTe₂ (0.70 eV per f.u.)⁵³. Such a barrier implies a high phase transition temperature. According to classical electromagnetic theory, the electrical field cannot switch the polarization in a polar metal because of the electron screening effects arising from the conduction electrons⁵⁴. But the situation may be different for the metallic FE–WZ' Tl₂NO₂ monolayer, in which the out-of-plane ferroelectricity could be switched by an electric field⁵⁴. In this sense, the FE–WZ' Tl₂NO₂ may be considered as a ferroelectric metal.

Similarly, the out-of-plane polarization can also exist in the FE -ZB' In₂NO₂ (Fig. 3b and Supplementary Fig. 22) and is calculated to be 2.75 μ C(cm)⁻² (Table 1). But note that FE–ZB' ln₂NO₂ is not a ferroelectric material because the centrosymmetric fcc phase is more stable in energy and thus the double-well potential¹⁶ is lacking. However, we find a strain-induced ferroelectricity in the FE $-ZB' \ln_2 NO_2$. Figure 3d shows the activation barriers in the polarization switching processes under different in-plane biaxial tensile strain. Remarkably, the centrosymmetric structure in the center of the minimum energy pathway gradually becomes unstable in energy with increasing strain. Evidently, two ferroelectric ground states with opposite electric polarizations can be found at the minima of the potential energy well under the biaxial tensile strain not less than 1%. Additionally, the classical doublewell potential can be found when the biaxial tensile strain is up to 5%. Furthermore, the activation barrier gets its maximum value of 0.14 eV under the biaxial strain of 4% and the corresponding electric polarization is about $2.79 \,\mu\text{C(cm)}^{-2}$ (Table 1). We also calculated the phonon spectra of the fcc and FE-ZB' In₂NO₂ monolayers under the strain of 4%. One can find apparent imaginary optical frequency modes occurring in the fcc phase but not in FE-ZB' phase (Supplementary Fig. 5), indicating a straininduced structural instability of the fcc phase. Such imaginaryfrequency modes activate a symmetry-lowering phase transition from the fcc to FE-ZB' phase, in which the off-center displacement of the magnetic N ion occurs. Therefore, the FE-ZB' In₂NO₂ monolayer could be tuned to be a ferroelectric metal by strain engineering. The changes of the total magnetic moments along the minimum energy pathways are shown in Supplementary Fig. 23. We find that the magnetic moments of the centrosymmetric paraelectric phases are slightly smaller than those of the corresponding ferroelectric phases.

Magnetoelectric effect in Tl₂NO₂/WTe₂ heterostructure

The coupling between the magnetic order and ferroelectric order, namely, the magnetoelectric effect, provides a way for the electric-field control of spin states and the magnetic-field control of charge states. It seems that there is no SOC-induced magnetoelectric coupling in FE-WZ' TI_2NO_2 monolayer because the easy plane is independent of the direction of electric polarization (Fig. 2c). However, we notice that the spin density of oxygen ions can be transferred between the top surface layer and the bottom surface layer (Fig. 2b) when the polarization is switched back and forth, which may introduce a magnetoelectric coupling through the interface effect.

Here, we propose 2H-WTe₂ to be an ideal substrate for FE-WZ' TI_2NO_2 , as the 2H phase WTe₂ monolayer has a small lattice mismatch (~1%) with the FE-WZ' TI_2NO_2 . Six different stacking configurations (Supplementary Fig. 24) of the FE-WZ' TI_2NO_2/WTe_2 vdW heterostructure were considered in our calculations. To simulate the epitaxial growth process of FE-WZ' TI_2NO_2 on WTe₂, we fixed the lattice constant of FE-WZ' TI_2NO_2 to match WTe₂ during the structural optimization. The AA1 pattern (Fig. 4a) with the polarization as it has the lowest binding energy (Supplementary Fig. 25). Remarkably, when the polarization is switched from downward to upward, the magnetic moment of AA1 decreases

from 0.95 μ_B to 0.9 μ_B , accompanied by the reduction of the interlayer distance and binding energy (Supplementary Figs. 25 and 26), which suggests an enhanced interaction between two layers. To understand this result, the charge density differences in spin-up and spin-down channel were calculated (Fig. 4a, b), which can be defined as⁵⁵ $\rho = \rho_{tot} - \rho_{TI_2NO_2} - \rho_{WTe_2}$, where ρ_{tot} , $\rho_{TI_2NO_2}$, and ρ_{WTe_2} are the electron densities of the heterostructure, isolated FE-WZ' TI_2NO_2 and isolated WTe_2, respectively. We can see that the electrons could transfer from 2H-WTe_2 to FE-WZ' TI_2NO_2, regardless of the polarization (downward or upward). However, when the polarization is switched from pointing downward to pointing upward, the transfer of spin-down electrons is significantly increased (Fig. 4a, b), which may lead to the redistribution of electrons in spin-up and spin-down channels in FE-WZ' TI_2NO_2 and the reduction of the total magnetic moment.

This spin-down electron transfer is also confirmed in the band structures (Fig. 4c, d). Obviously, the spin-down states around K point from FE-WZ' TI_2NO_2 and 2H-WTe₂ are hybridized near the Fermi level in the band structure of TI_2NO_2 /WTe₂ with an 'up' polarization (Fig. 4c), in contrast to the situation with a 'down' polarization (Fig. 4d). This result implies a possible electric-field control of spin states in the TI_2NO_2 /WTe₂ heterostructure via the interface effect.

In summary, an possible strategy to design two-dimensional multiferroics without the d⁰-rule requirements has been reported in a family of stable 2D MXene-analogous oxynitrides, X_2NO_2 (X = In, TI). Distinct from all previous cases, the ferroelectricity and intrinsic *p*-orbital ferromagnetism can stem from the same ion, which naturally circumvents the incompatibility between ferroelectricity and magnetism usually seen in *d*-electron based multiferroics. The strong ferromagnetic metallic states might be maintained above room temperature owing to the relatively localized nature of the itinerant 2*p* states. Furthermore, the charge transfer between TI₂NO₂ and WTe₂ in their heterostructure can lead to an electric-field control of spin states. Our findings may pave an alternative way to the design of the 2D multiferroics and the discovery of ferroelectric metals.

METHODS

Computational details

Our density functional theory calculations⁵⁶ were carried out using the Vienna ab initio Simulation Package code⁵⁷. The electron-ion interaction was treated by the projector augmented wave method⁵⁸. The Perdew-Burke-Ernzerhof version of the generalized gradient approximation was used for the exchange-correlation functional⁴². The Heyd–Scuseria–Ernzerhof hybrid functional (HSE06) was employed to obtain accurate electronic band structures⁴³ To avoid the interaction between the periodic images, a vacuum region more than 15 Å along the z-direction was set. The plane-wave cutoff energies were set as 520 eV. Meanwhile, for the Brillouin zone sampling, a 16×16×1 and $10 \times 10 \times 1$ Γ -centered Monkhorst–Pack k point mesh were used for the PBE and HSE06 calculations, respectively⁵⁹. The convergence criterion for energy was set to 10⁻⁸ eV and ionic relaxation was carried out with a force tolerance of 0.001 eVÅ⁻¹. The dipole correction⁶⁰ was adopted for the calculation of the out-of-plane electric dipole moment³². The phonon spectra were calculated using a linear response approach⁶¹ with the PHONOPY code⁶². To investigate the thermodynamic stability of the monolayers, AIMD simulations were carried out using the canonical ensemble³⁸ with a $5 \times 5 \times 1$ supercell at 300 K with a time step of 1 fs. The climbing image nudged elastic band method⁶³ was implemented to obtain the energy barriers in the structural transitions. The SOC effect was also considered in band structure calculations, which yields no significant effect. The formation energy of X2NO2 monolayers is described as $E_{\rm f}=(E_{\rm X_2NO_2}-2\mu_{\rm X}-\mu_{\rm N}-2\mu_{\rm O})/5$, where $E_{\rm X_2NO_2}$ is the total energy and $\mu_{\rm X},\,\mu_{\rm N},\,{\rm and}\,\,\bar{\mu_{\rm O}}$ are chemical potentials determined by the most stable X crystal, gas phase N_{2r} and O_{2r} respectively. The vdW interaction between Tl_2NO_2 and WTe_2 monolayers was described by the DFT-D3 method³⁵. The binding energies of the Tl_2NO_2/WTe_2 heterostructures can be defined as⁵⁵ $E_b = E_{tot} - E_{Tl_2NO_2} - E_{WTe_2}$, where E_{tot} , $E_{Tl_2NO_2}$, and E_{WTe_2} are the energies of the heterostructure, Tl₂NO₂, and WTe₂, respectively. To estimate



Fig. 4 A possible magnetoelectric effect in Tl_2NO_2/WTe_2 heterostructure. **a**, **b** The charge density differences in spin-up and spin-down channels for Tl_2NO_2/WTe_2 heterostructure with polarization directions pointing (**a**) upward and (**b**) downward. Red, wathet, gray, orange, and green spheres denote O, N, Tl, Te, and W atoms, respectively. The green arrows denote the direction of polarizations. The interlayer distance is donated by *d*. (**c**, **d**) The spin-resolved band structure of the Tl_2NO_2/WTe_2 heterostructure with polarization directions pointing (**c**) upward and (**d**) downward. The orange and violet lines indicate the spin-up and spin-down bands contributed by Tl_2NO_2 monolayer, respectively. The sizes of the red and green dots represent the weights of spin-up and spin-down states contributed by the WTe₂ monolayer, respectively.

the Curie temperature, the Monte Carlo simulations based on the Heisenberg model were performed using MCSOLVER⁶⁴.

DATA AVAILABILITY

All relevant data are available from the corresponding author upon reasonable request.

CODE AVAILABILITY

All non-commercial numerical codes to reproduce the findings of this study are available from the corresponding author upon reasonable request.

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AUTHOR CONTRIBUTIONS

H.P. conceived the idea and supervised the project. H.A. carried out first-principles calculations and conducted Monte Carlo simulations. H.A., H.P., and K.H.L. co-wrote the paper. All authors discussed the results and commented on the manuscript together.

COMPETING INTERESTS

The authors declare no competing interests.

ADDITIONAL INFORMATION

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